

## Crystal structures of ternary gadolinium silicides

V. Mykhalichko,<sup>1</sup> R. Kozak,<sup>2</sup> P. Demchenko,<sup>1</sup> and R. Gladyshevskii<sup>1</sup>

<sup>1</sup>*Department of Inorganic Chemistry,  
Ivan Franko National University of Lviv,  
Kyryla i Mefodiya St. 6, UA-79005 Lviv, Ukraine*

<sup>2</sup>*Laboratory of Crystallography, Department of Materials,  
ETH Zurich, Vladimir-Prelog-Weg 5, CH-8093 Zurich, Switzerland*

The crystal structure of  $\text{Gd}_2\text{Re}_3\text{Si}_5$  was solved by direct methods in space group  $P4/mnc$ , using the SHELX-97 program package. The crystal structure of  $\text{Gd}_2\text{Pt}_3\text{Si}_5$  was refined by the Rietveld method, using the CSD program package. The crystal structure of the ternary compound  $\text{Gd}_2\text{Re}_3\text{Si}_5$  belongs to the structure type  $\text{U}_2\text{Mn}_3\text{Si}_5$  ( $tP40$ ,  $P4/mnc$ ,  $a = 10.95564(13)$ ,  $c = 5.56326(11)$  Å, atom coordinates: Gd  $8h$  0.26249(5) 0.42271(5) 0; Re1  $8h$  0.14676(4) 0.12315(4) 0; Re2  $4d$  0 1/2 1/4; Si1  $8h$  0.0267(3) 0.3149(3) 0; Si2  $8g$  0.17183(18) 0.67183(18) 1/4; Si3  $4e$  0 0 0.2567(9)), whereas the crystal structure of  $\text{Gd}_2\text{Pt}_3\text{Si}_5$  adopts the  $\text{U}_2\text{Co}_3\text{Si}_5$  type ( $oI40$ ,  $Ibam$ ,  $a = 9.9224(2)$ ,  $b = 11.3997(2)$ ,  $c = 5.99300(9)$  Å, atom coordinates: Gd  $8j$  0.2671(2) 0.3717(3) 0; Pt1  $8j$  0.1122(2) 0.1374(2) 0; Pt2  $4b$  1/2 0 1/4; Si1  $8j$  0.356(1) 0.116(1) 0; Si2  $8g$  0 0.2710(9) 1/4; Si3  $4a$  0 0 1/4). The structures of  $\text{Gd}_2\text{Re}_3\text{Si}_5$  and  $\text{Gd}_2\text{Pt}_3\text{Si}_5$  can be described as arrangements of one-dimensional structural columns parallel to the crystallographic direction [001], also found in the structure type  $\text{CaBe}_2\text{Ge}_2$ .